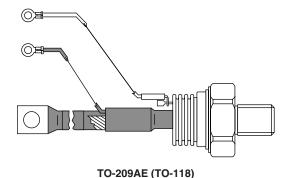


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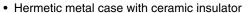
Phase Control Thyristors (Stud Version), 330 A



PRODUCT SUMMARY		
I _{T(AV)}	330 A	

FEATURES

- · Center amplifying gate
- International standard case TO-209AE (TO-118)





- Compression bonded encapsulation for heavy duty operations such as severe thermal cycling
- Lead (Pb)-free
- Designed and qualified for industrial level

TYPICAL APPLICATIONS

- · DC motor controls
- Controlled DC power supplies
- AC controllers

MAJOR RATINGS AND CHARACTERISTICS				
PARAMETER	TEST CONDITIONS	VALUES	UNITS	
1		330	A	
$I_{T(AV)}$	T _C	75	°C	
I _{T(RMS)}		520		
	50 Hz	9000	Α	
I _{TSM}	60 Hz	9420		
12)	50 Hz	405	kA ² s	
I ² t	60 Hz	370	KA-S	
V _{DRM} /V _{RRM}		400 to 2000	V	
t _q	Typical	100	μs	
T _J		- 40 to 125	°C	

ELECTRICAL SPECIFICATIONS

VOLTAGE R	VOLTAGE RATINGS							
TYPE NUMBER	VOLTAGE CODE	V _{DRM} /V _{RRM} , MAXIMUM REPETITIVE PEAK AND OFF-STATE VOLTAGE V	V _{RSM} , MAXIMUM NON-REPETITIVE PEAK VOLTAGE V	I_{DRM}/I_{RRM} MAXIMUM AT $T_J = T_J$ MAXIMUM mA				
	04	400	500					
	08	800	900					
ST330S	12	1200	1300	50				
	16	1600	1700					
	20	2000	2100					

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ST330SPbF Series

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ABSOLUTE MAXIMUM RATIN	GS					
PARAMETER	SYMBOL		TEST CONDITIONS		VALUES	UNITS
Maximum average on-state current		180° condu	180° conduction, half sine wave		330	Α
at case temperature	$I_{T(AV)}$				75	°C
Maximum RMS on-state current	I _{T(RMS)}	DC at 75 °C	case temperati	ure	520	
		t = 10 ms	No voltage		9000	
Maximum peak, one-cycle		t = 8.3 ms	reapplied		9420	A kA ² s
non-repetitive surge current	I _{TSM}	t = 10 ms	100 % V _{RRM}		7570	
		t = 8.3 ms	reapplied	Sinusoidal half wave,	7920	
Maximum I ² t for fusing	l ² t	t = 10 ms	No voltage	initial $T_J = T_J$ maximum	405	
		t = 8.3 ms	reapplied		370	
		t = 10 ms	100 % V _{RRM}		287	
		t = 8.3 ms	reapplied		262	
Maximum I ² √t for fusing	I ² √t	t = 0.1 to 10	ms, no voltage	reapplied	4050	kA²√s
Low level value of threshold voltage	V _{T(TO)1}	(16.7 % x π	$x I_{T(AV)} < I < \pi x$	$I_{T(AV)}$, $T_J = T_J$ maximum	0.834	V
High level value of threshold voltage	V _{T(TO)2}	$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$		0.898	V	
Low level value of on-state slope resistance	r _{t1}	(16.7 % x π x $I_{T(AV)}$ < I < π x $I_{T(AV)}$), $I_J = I_J$ maximum		0.687	m 0	
High level value of on-state slope resistance	r _{t2}	$(I > \pi \times I_{T(AV)}), T_J = T_J \text{ maximum}$		0.636	mΩ	
Maximum on-state voltage	V_{TM}	$I_{pk} = 1000 \text{ A}, T_J = T_J \text{ maximum}, t_p = 10 \text{ ms sine pulse}$		1.52	V	
Maximum holding current	l _Η	T _ 05 °C	anada aunnis 1	2 V registive lead	600	m A
Typical latching current	ΙL	1 J = 25 °C,	anoue supply 17	2 V resistive load	1000	mA

SWITCHING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum non-repetitive rate of rise of turned-on current	dI/dt	Gate drive 20 V, 20 Ω , $t_r \le 1~\mu s$ $T_J = T_J$ maximum, anode voltage $\le 80~\%~V_{DRM}$	1000	A/µs
Typical delay time	t _d	Gate current A, $dl_g/dt = 1$ A/ μ s $V_d = 0.67 \% V_{DRM}$, $T_J = 25 °C$	1.0	
Typical turn-off time	tq	$I_{TM} = 550 \text{ A, } T_J = T_J \text{ maximum, } dI/dt = 40 \text{ A/}\mu\text{s,}$ $V_R = 50 \text{ V, } dV/dt = 20 \text{ V/}\mu\text{s, } \text{gate } 0 \text{ V } 100 \Omega\text{, } t_p = 500 \mu\text{s}$	100	μs

BLOCKING				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum critical rate of rise of off-state voltage	dV/dt	$T_J = T_J$ maximum linear to 80 % rated V_{DRM}	500	V/µs
Maximum peak reverse and off-state leakage current	I _{RRM,} I _{DRM}	$T_J = T_J$ maximum, rated V_{DRM}/V_{RRM} applied	50	mA



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TRIGGERING						
PARAMETER	SYMBOL	TEST SOURITIONS		VALUES		UNITS
PARAMETER	STINIBUL	I E	ST CONDITIONS	TYP.	MAX.	UNITS
Maximum peak gate power	P _{GM}	$T_J = T_J$ maximum,	t _p ≤ 5 ms	10	0.0	w
Maximum average gate power	P _{G(AV)}	$T_J = T_J$ maximum,	f = 50 Hz, d% = 50	2	.0	VV
Maximum peak positive gate current	I _{GM}	$T_J = T_J$ maximum,	t _p ≤ 5 ms	3	.0	Α
Maximum peak positive gate voltage	+ V _{GM}	T - T movimum	+ < 5 mg	20		V
Maximum peak negative gate voltage	- V _{GM}	ij= ijiliaxililulli,	$T_J = T_J$ maximum, $t_p \le 5$ ms		.0	
	I _{GT}	T _J = - 40 °C	Maximum required gate trigger/	200	-	
DC gate current required to trigger		T _J = 25 °C		100	200	mA
		T _J = 125 °C	current/voltage are the lowest	50	-	
	V _{GT}	T _J = - 40 °C	value which will trigger all units	2.5	-	
DC gate voltage required to trigger		T _J = 25 °C	12 V anode to cathode applied	1.8	3	٧
		T _J = 125 °C		1.1	-]
DC gate current not to trigger	I _{GD}	T - T movimum	Maximum gate current/voltage not to trigger is the maximum	1	0	mA
DC gate voltage not to trigger	V _{GD}	ıj=ıj maximum	$T_J = T_J$ maximum value which will not trigger any unit with rated V_{DRM} anode to cathode applied		0.25	

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS	
Maximum operating junction temperature range	T _J		- 40 to 125	°C	
Maximum storage temperature range	T _{Stg}		- 40 to 150		
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	0.10	K/W	
Maximum thermal resistance, case to heatsink	R _{thC-hs}	Mounting surface, smooth, flat and greased	0.03	I N/VV	
Mounting torque, ± 10 %		Non-lubricated threads	48.5 (425)	$N \cdot m$ (lbf \cdot in)	
Approximate weight			535	g	
Case style		See dimension - link at the end of datasheet	TO-209AE (TO-118)	

△R _{thJC} CONDUCTION					
CONDUCTION ANGLE	SINUSOIDAL CONDUCTION	RECTANGULAR CONDUCTION	TEST CONDITIONS	UNITS	
180°	0.011	0.008			
120°	0.013	0.014			
90°	0.017	0.018	$T_J = T_J$ maximum	K/W	
60°	0.025	0.026			
30°	0.041	0.042			

Note

 $\bullet \ \ \, \text{The table above shows the increment of thermal resistance } \, R_{thJC} \, \text{when devices operate at different conduction angles than DC} \,$

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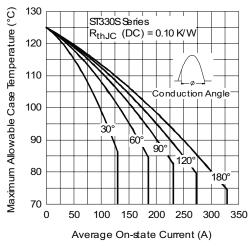


Fig. 1 - Current Ratings Characteristics

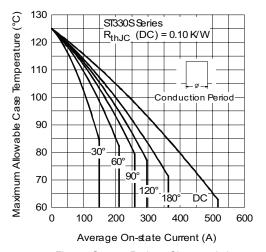


Fig. 2 - Current Ratings Characteristics

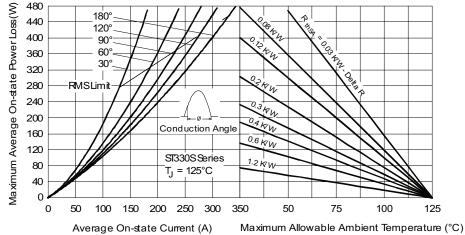
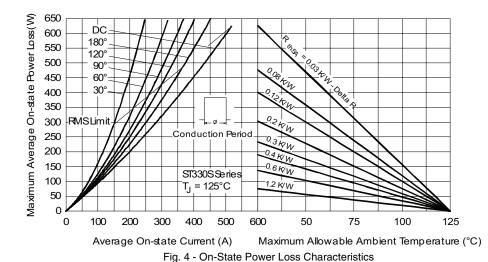


Fig. 3 - On-State Power Loss Characteristics



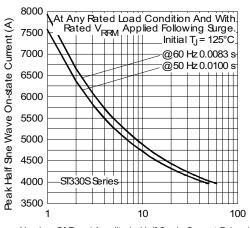
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Number Of Equal Amplitude Half Cycle Current Pulses (N) Fig. 5 - Maximum Non-Repetitive Surge Current

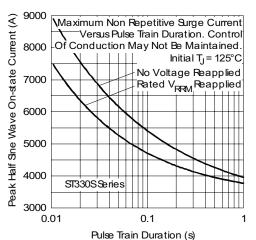


Fig. 6 - Maximum Non-Repetitive Surge Current

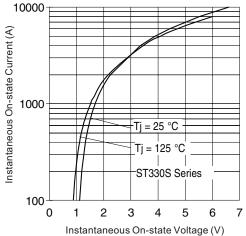


Fig. 7 - On-State Voltage Drop Characteristics

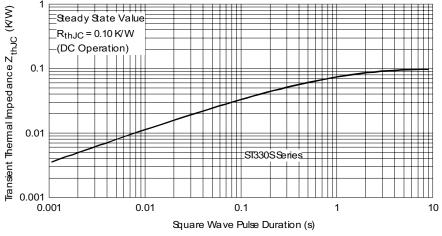
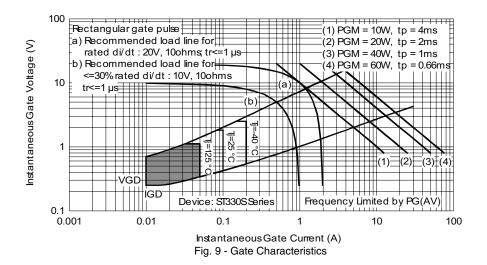


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics

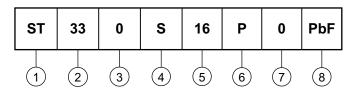
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ORDERING INFORMATION TABLE

Device code



1 - Thyristor

2 - Essential part number

3 - 0 = Converter grade

4 - S = Compression bonding stud

Voltage code x 100 = V_{RRM} (see Voltage Ratings table)

P = Stud base 3/4"-16UNF-2A threads

7 - 0 = Eyelet terminals (gate and auxiliary cathode leads)

1 = Fast-on terminals (gate and auxiliary cathode leads)

8 - Lead (Pb)-free

LINKS TO RELAT	TED DOCUMENTS
Dimensions	http://www.vishay.com/doc?95080

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